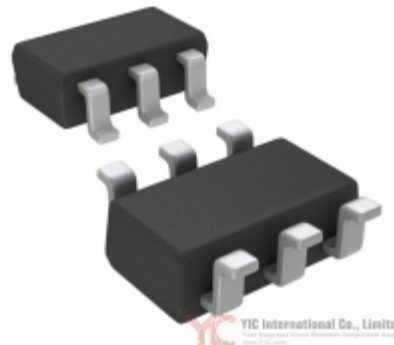


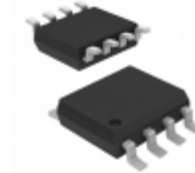





	<h2 style="color: red;">NVGS3443T1G</h2> <p><b>Hersteller-Teilenummer:</b> NVGS3443T1G</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 20V 2A 6-TSOP</p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 41131 pcs Stock Available.</p> <p><b>Lieferr von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	NVGS3443T1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 20V 2A 6-TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	41131 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	-
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.1A (Ta)
Rds On (Max) @ Id, Vgs	65 mOhm @ 4.4A, 4.5V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	565pF @ 5V
Verpackung	Tape & Reel (TR)

NVGS3443T1G ist neu im Original, Suche NVGS3443T1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NVGS3443T1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NVGS3443T1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>IRF5803D2</b> International Rectifier (Infineon Technologies) MOSFET P-CH 40V 3.4A 8-SOIC</p>	 <p><b>NVGS4141NT1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 3.5A 6TSOP</p>	 <p><b>AO4441L_001</b> Alpha and Omega Semiconductor, Inc. MOSFET P-CH 60V 8SOIC</p>	 <p><b>NVGS4111PT1G</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 30V 3.7A 6TSOP</p>
 <p><b>NVGS5120PT1G</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 1.8A 6TSOP</p>	 <p><b>NVGS3130N</b> AMI Semiconductor / ON Semiconductor NVGS3130N ON</p>	 <p><b>NVGS3130NT1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V 4.2A 6TSOP</p>	 <p><b>NVGS3441T1G</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.35A 6-TSOP</p>

### heiße Teile

Mehr

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AP1117Y25G-13	AP6900GSM	BA7078AF-E2	CDT100GK20	CGA5L3X8R1H684K160AE
CM2576ZJCN263TR	CR0805-J/-4R7ELF	EGL41B-5400	GQM1875C2E680GB12D	GRM188R72A682KA01J
D ISO7240ADWR	KDS122-RTK/P	LM3533TMX-40	LM3937ITLX-2.85	LT1247CS8#PBF
M24C01-WBN6	MAX15004AAUE/V+T	MCP42100-I/P	MEV-50B-R	MIG30J902H
MP4021-A	NRS5040T2R2NMGJ	D NVGS3130N	NVGS3130NT1G	NVGS3136PT1G
NVGS3441T1G	D NVGS4111PT1G	NVGS4141NT1G	NVGS5120PT1G	PA-AC-70W
PKF2611SI	R2A30232ASP	R5F212K2SNFP	RF505BM6SFH	SBR2U30SA-13-F
SE100280DPR	STF7NM60N	T510S12TSC	D T7S0027504JB	TC58C256AXB
TC74LVX74F	TOP224GN-TL	TSC6966DCA	TW8816-LB3-GR	V375B12T300A

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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